

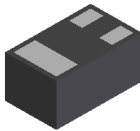
Features

- $BV_{CEO} > -40V$
- $I_C = -500mA$ High Collector Current
- $I_{CM} = -1A$ Peak Pulse Current
- $P_D = 1000mW$ Power Dissipation
- Low Collector-Emitter Saturation Voltage, $V_{CE(sat)}$
- $0.60mm^2$ Package Footprint, 13 times Smaller than SOT23
- 0.5mm Height Package Minimizing Off-Board Profile
- Complementary NPN Type DSS2540M
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

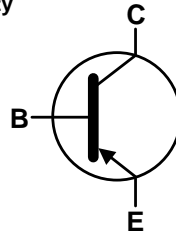
Mechanical Data

- Case: X1-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish — NiPdAu e4
- Solderable per MIL-STD-202, Method 208
- Weight: 0.0009 grams (Approximate)

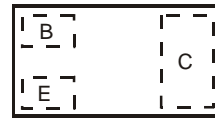
X1-DFN1006-3



Bottom View



Device Symbol


 Top View
Device Schematic

Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DSS3540M-7	TD	7	8	3,000
DSS3540M-7B	TD	7	8	10,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com>.

Marking Information

DSS3540M-7	<div style="display: flex; justify-content: space-around;"> <div style="text-align: center;"> <p>Top View Dot Denotes Collector Side</p> </div> <div style="text-align: center;"> <p>From date code 1527 (YYWW), this changes to:</p> <p>Top View Bar Denotes Base and Emitter Side</p> </div> </div>
DSS3540M-7B	<div style="text-align: center;"> <p>Top View Bar Denotes Base and Emitter Side</p> </div> <p style="text-align: right;">TD = Product Type Marking Code</p>

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-6	V
Collector Current - Continuous	I _C	-500	mA
Peak Pulse Collector Current	I _{CM}	-1	A
Peak Base Current	I _{BM}	-100	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

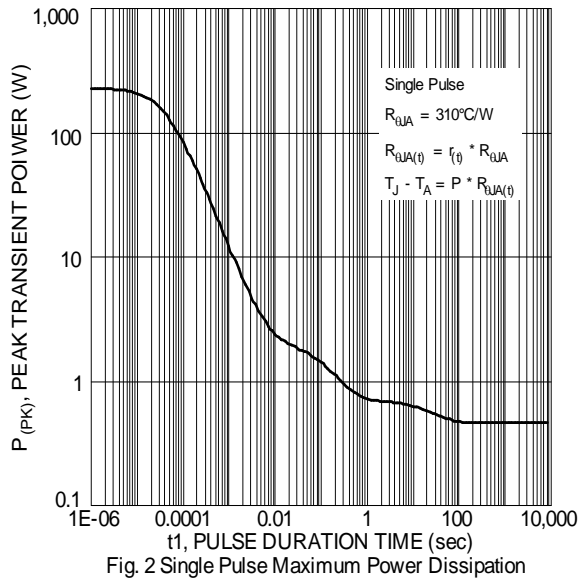
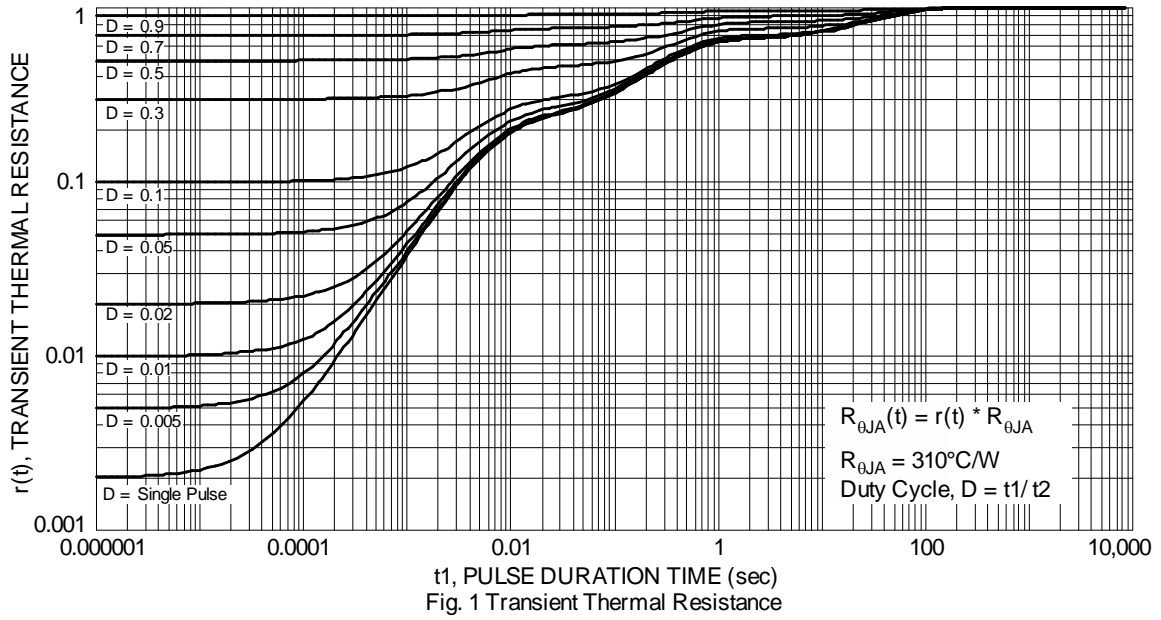
Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	(Note 5) 400	mW
		(Note 6) 1,000	
Thermal Resistance, Junction to Ambient	R _{θJA}	(Note 5) 310	°C/W
		(Note 6) 120	
Thermal Resistance, Junction to Lead	R _{θJL}	120	°C/W
Operating and Storage and Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	B

- Notes:
5. For the device mounted on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady state condition. The entire exposed collector pad is attached to the heatsink.
 6. Same as Note 5, except the exposed collector pad is mounted on 25mm x 25mm 2oz copper.
 7. Thermal resistance from junction to solder-point (on the exposed collector pad).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	-40	—	—	V	I _C = -100μA, I _E = 0
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-40	—	—	V	I _C = -10mA, I _B = 0
Emitter-Base Breakdown Voltage	BV _{EBO}	-6	—	—	V	I _E = -100μA, I _C = 0
Collector-Base Cutoff Current	I _{CBO}	—	—	-100 -50	nA μA	V _{CB} = -30V, I _E = 0 V _{CB} = -30V, I _E = 0, T _A = +150°C
Emitter-Base Cutoff Current	I _{EBO}	—	—	-100	nA	V _{EB} = -5V, I _C = 0
Collector-Emitter Cutoff Current	I _{CEX}	—	—	-100 -100	nA	V _{CE} = -30V, V _X = ±0.25V V _{CE} = -30V, V _X = 3V
Collector-Emitter Cutoff Current	I _{CES}	—	—	-100	nA	V _{CE} = -30V
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h _{FE}	200 150 40	— — —	— — —	—	V _{CE} = -2V, I _C = -10mA V _{CE} = -2V, I _C = -100mA V _{CE} = -2V, I _C = -500mA
Collector-Emitter Saturation Voltage	V _{CE(sat)}	— — — —	— — — —	-50 -130 -200 -350	mV	I _C = -10mA, I _B = -0.5mA I _C = -100mA, I _B = -5mA I _C = -200mA, I _B = -10mA I _C = -500mA, I _B = -50mA
Collector-Emitter Saturation Resistance	R _{CE(sat)}	—	—	700	mΩ	I _C = -500mA, I _B = -50mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	—	—	-1.2	V	I _C = -500mA, I _B = -50mA
Base-Emitter Turn On Voltage	V _{BE(on)}	—	—	-1.1	V	V _{CE} = -2V, I _C = -100mA
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C _{obo}	—	—	10	pF	V _{CB} = -10V, f = 1.0MHz
Current Gain-Bandwidth Product	f _T	100	—	—	MHz	V _{CE} = -5V, I _C = -100mA, f = 100MHz

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

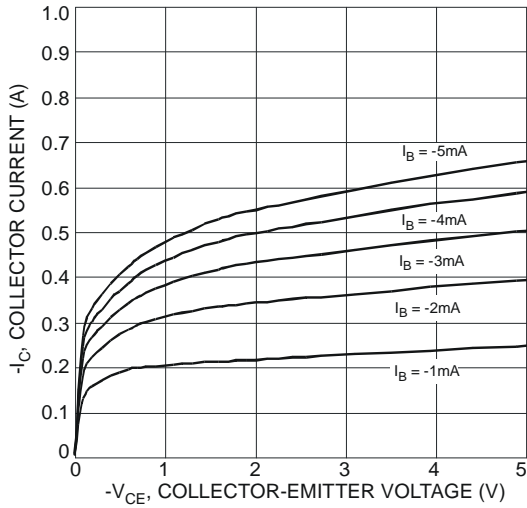


Fig. 4 Typical Collector Current vs. Collector-Emitter Voltage

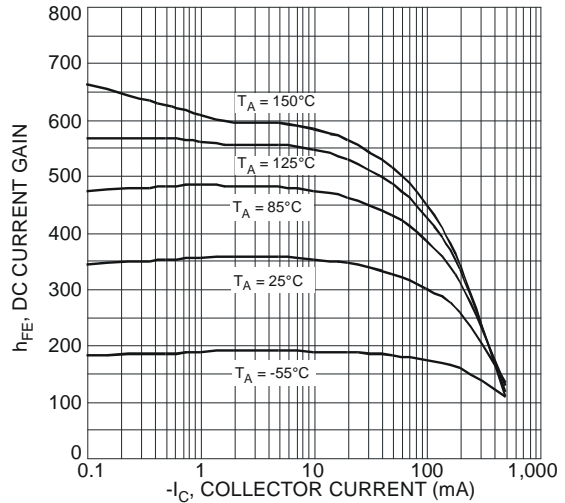


Fig. 5 Typical DC Current Gain vs. Collector Current

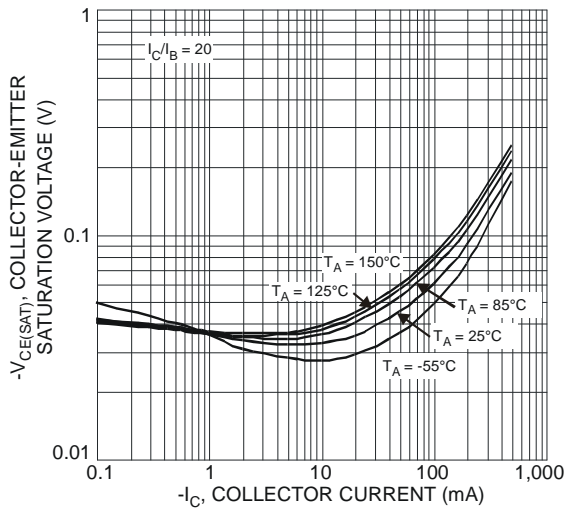


Fig. 6 Typical Collector-Emitter Saturation Voltage vs. Collector Current

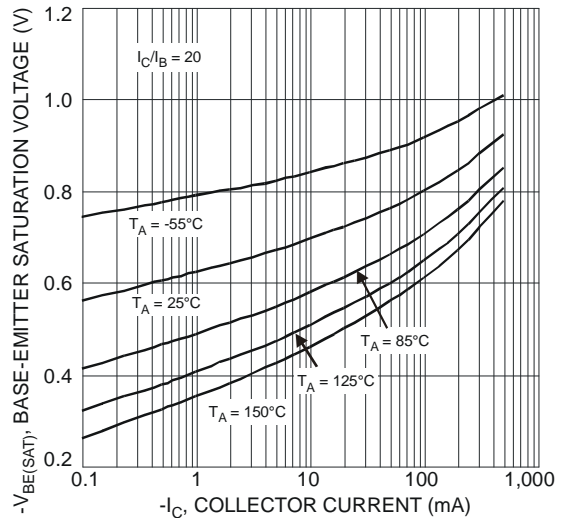


Fig. 7 Typical Base-Emitter Saturation Voltage vs. Collector Current

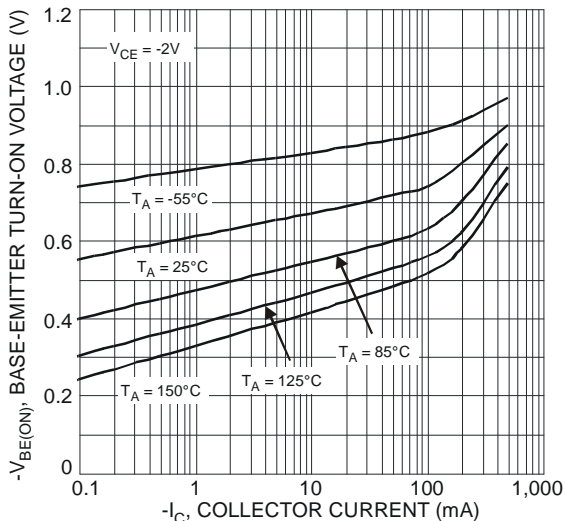


Fig. 8 Typical Base-Emitter Turn-On Voltage vs. Collector Current

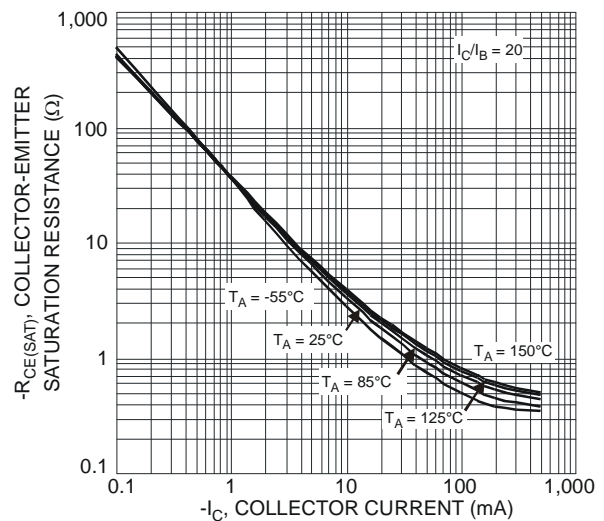
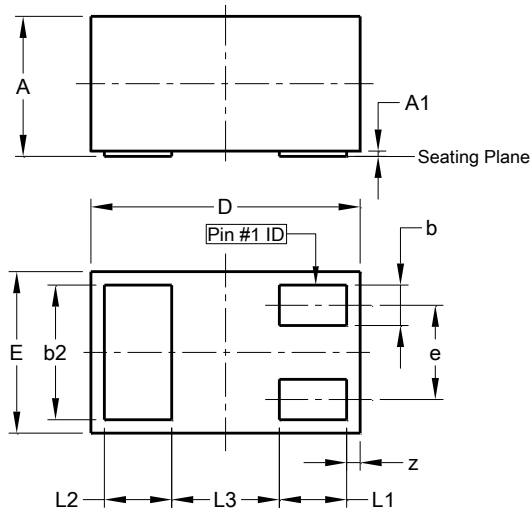


Fig. 9 Typical Collector-Emitter Saturation Resistance vs. Collector Current

Package Outline Dimensions

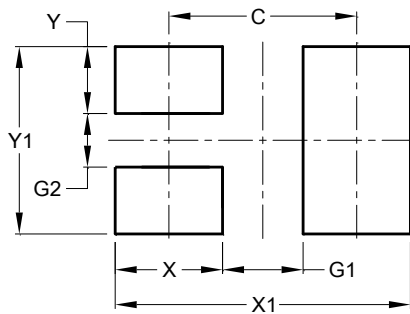
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



X1-DFN1006-3			
Dim	Min	Max	Typ
A	0.47	0.53	0.50
A1	0.00	0.05	0.03
b	0.10	0.20	0.15
b2	0.45	0.55	0.50
D	0.95	1.075	1.00
E	0.55	0.675	0.60
e	-	-	0.35
L1	0.20	0.30	0.25
L2	0.20	0.30	0.25
L3	-	-	0.40
z	0.02	0.08	0.05
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	0.70
G1	0.30
G2	0.20
X	0.40
X1	1.10
Y	0.25
Y1	0.70

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